

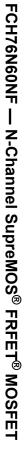
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November 2013

FCH76N60NF N-Channel SupreMOS[®] FRFET[®] MOSFET 600 V, 72.8 A, 38 mΩ

Features

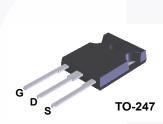
- R_{DS(on)} = 28.7 mΩ (Typ.) @ V_{GS} = 10 V, I_D = 38 A
- Ultra Low Gate Charge (Typ. Q_g = 230 nC)
- Low Effective Output Capacitance (Typ. C_{oss(eff.)} = 896 pF)
- 100% Avalanche Tested
- RoHS Compliant

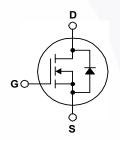
Application

- Solar Inverter
- AC-DC Power Supply

Description

The SupreMOS[®] MOSFET is Fairchild Semiconductor's next generation of high voltage super-junction (SJ) technology employing a deep trench filling process that differentiates it from the conventional SJ MOSFETs. This advanced technology and precise process control provides lowest Rsp on-resistance, superior switching performance and ruggedness. SupreMOS MOSFET is suitable for high frequency switching power converter applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications. SupreMOS FRFET[®] MOSFET's optimized body diode reverse recovery performance can remove additional component and improve system reliability.





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

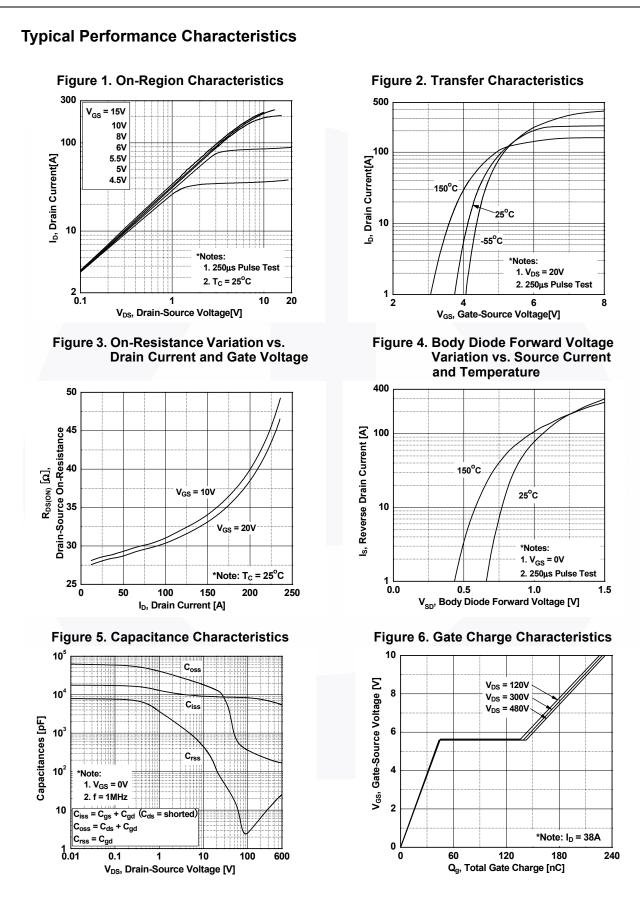
Symbol	Parameter			FCH76N60NF	Unit
V _{DSS}	Drain to Source Voltage			600	V
V _{GSS}	Gate to Source Voltage			±30	V
ID	Drain Current	- Continuous (T _C = 25 ^o C)		72.8	
		- Continuous (T _C = 100 ^o C)		46	Α
I _{DM}	Drain Current	- Pulsed (No	ote 1)	218	А
E _{AS}	Single Pulsed Avalanche Energy (Note 2)			7381	mJ
I _{AR}	Avalanche Current (Note 1)			24.3	А
E _{AR}	Repetitive Avalanche Energy (Note 1		ote 1)	5.43	mJ
-1/-14	MOSFET dv/dt			100	V/ns
dv/dt	Peak Diode Recovery dv/dt (Note 3)			50	
P _D	Power Dissipation	(T _C = 25 ^o C)		543	W
		- Derate above 25°C		4.34	W/ ^o C
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		S	300	°C

Thermal Characteristics

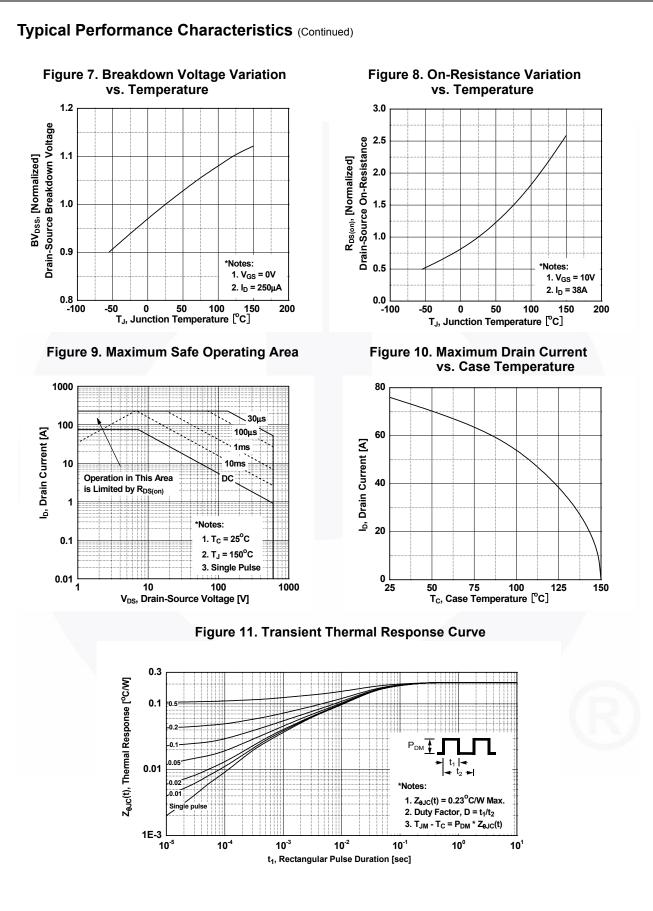
Symbol	Symbol Parameter		Unit
$R_{ extsf{ heta}JC}$	C Thermal Resistance, Junction to Case, Max.		°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	40	

1

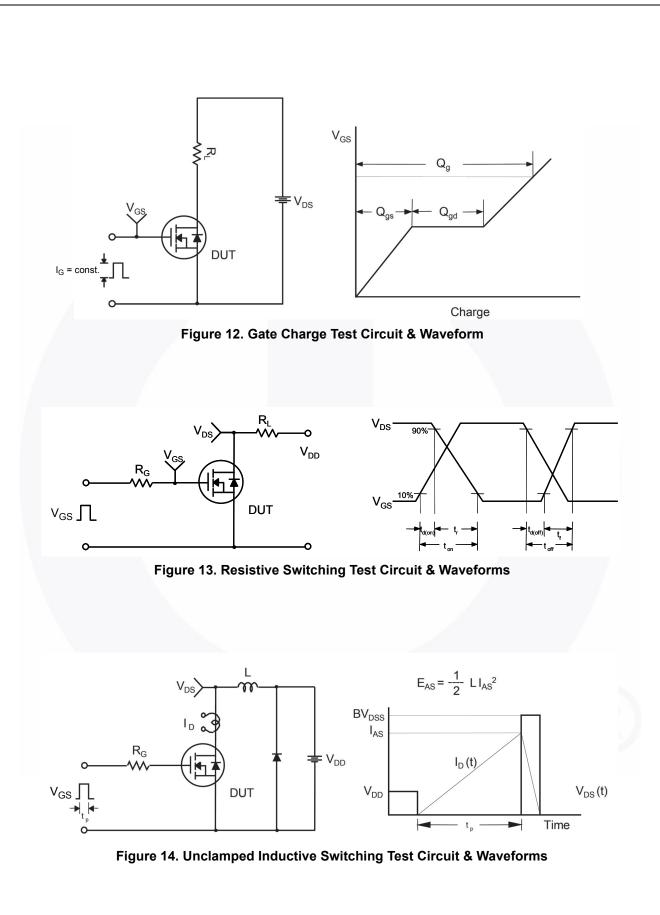
Part Nur	nber	Top Mark	Package	Packing Method	Reel Size	•	Tape Width	Qu	antity	
FCH76N	60NF	FCH76N60NF	TO-247	Tube	N/A		N/A	30	units	
Electrica	l Chara	I cteristics T _c = 25°C u	nless other	wise noted.						
Symbol		Parameter		Test Conditions	\$	Min.	Тур.	Max.	Unit	
Off Charac	teristics									
BV _{DSS}	Drain to S	Source Breakdown Voltage	I _D =	1 mA, V _{GS} = 0 V, T _C =	= 25°C	600	-	-	V	
ΔΒV _{DSS} / ΔΤ _J	Breakdow Coefficier	wn Voltage Temperature nt	I _D =	1 mA, Referenced to	25°C	-	0.73	-	V/ºC	
	Zero Gat	e Voltage Drain Current		= 480 V, V_{GS} = 0 V		-	-	10		
IDSS	Zero Gat	e voltage Drain Guirent		= 480 V, V_{GS} = 0 V, T	_C = 125 ^o C	-	-	100	μA	
I _{GSS}	Gate to E	Body Leakage Current	V _{GS}	$= \pm 30 \text{ V}, \text{ V}_{\text{DS}} = 0 \text{ V}$		-	-	±100	nA	
On Charac	teristics									
V _{GS(th)}	Gate Thr	eshold Voltage	V _{GS}	_s = V _{DS} , I _D = 250 μA		3.0	-	5.0	V	
R _{DS(on)}	Static Dra	ain to Source On Resistance		s = 10 V, I _D = 38 A		-	28.7	38.0	mΩ	
9 _{FS}	Forward	Transconductance		= 20 V, I _D = 38 A		-	92	-	S	
Dynamic C	horooto	riation								
-	1						9205	11045	~ Г	
C _{iss}	Input Cap		VDS	V _{DS} = 100 V, V _{GS} = 0 V f = 1 MHz		-	8305	11045	pF	
C _{oss}	-	apacitance				-	361	480	pF	
C _{rss}		Transfer Capacitance	V	= 280 V V = 0 V f		-	3.3 192	5.0	pF pF	
C _{oss}		apacitance	-	$_{\rm S} = 380$ V, V _{GS} = 0V, f =		-	896	-	pr pF	
C _{oss(eff.)}		Output Capacitance e Charge at 10V		$V_{DS} = 0 V \text{ to } 380 V, V_{GS} = 0 V$ $V_{DS} = 380 V, I_D = 38 A,$ $V_{GS} = 10 V$ (Note 4)		-	230	- 300	nC	
Q _{g(tot)}		-				-	44	300	nC	
Q _{gs}	-	Source Gate Charge	VGS			-	95	-	nC	
Q _{gd} ESR		nt Series Resistance(G-S)	f _ /	1 MHz	(11010-1)	-	95	-	Ω	
	·		=			-	1.2	-	52	
Switching										
t _{d(on)}		Delay Time	N N	V_{DD} = 380 V, I _D = 38 A R _G = 4.7 Ω		-	51	112	ns	
t _r		Rise Time	00			-	44	98	ns	
t _{d(off)}		Delay Time				-	213	436	ns	
t _f	Turn-Off I	Fall Lime			(Note 4)	-	43	96	ns	
Drain-Sour	ce Diod	e Characteristics								
I _S	Maximum Continuous Drain to Source Diode Forward Current					-	-	76	A	
I _{SM}	Maximum	Maximum Pulsed Drain to Source Diode F		orward Current		-	-	228	Α	
V _{SD}	Drain to S	Source Diode Forward Voltag	e V _{GS} = 0 V, I _{SD} = 38 A			-	-	1.2	V	
t _{rr}	Reverse I	Recovery Time		$V_{GS} = 0 \text{ V}, \text{ I}_{SD} = 38 \text{ A}$ $d\text{I}_F/dt = 100 \text{ A}/\mu\text{s}$		-	200	-	ns	
Q _{rr}	Reverse I	Recovery Charge	dl _E /o			-	1.8	-	μC	

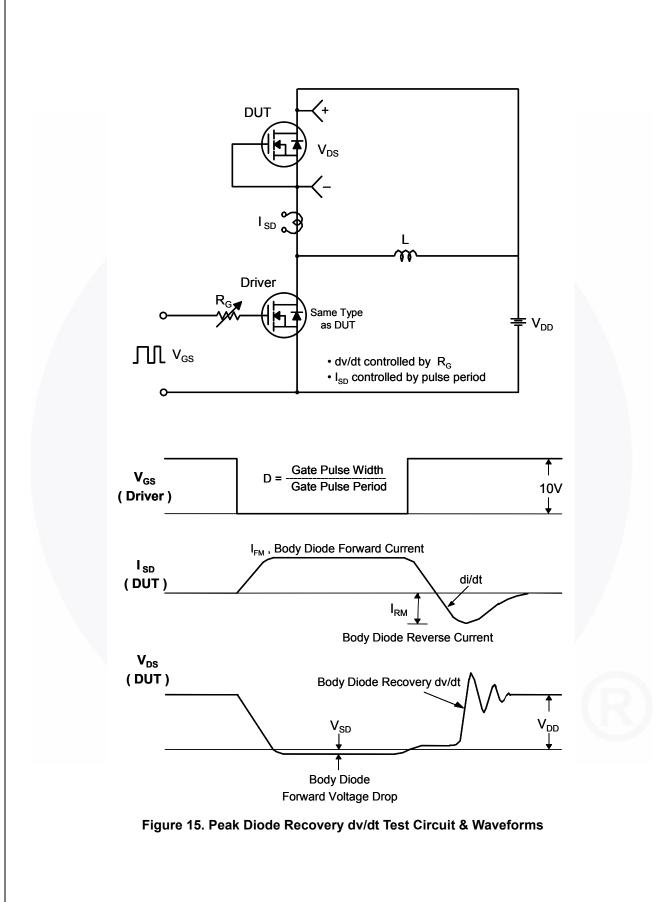


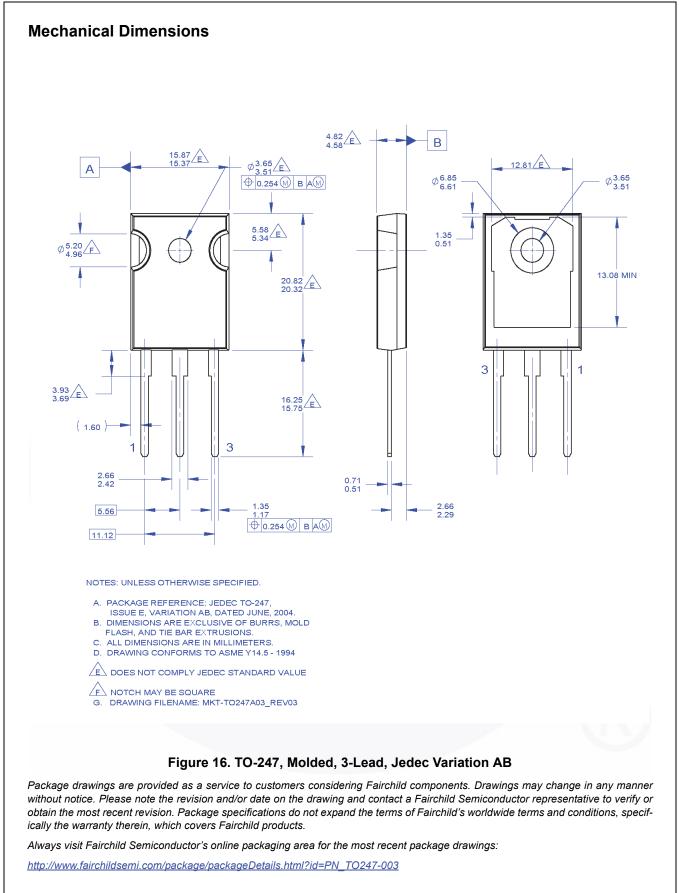
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